**TGBR30U50 DIODE** 

# TRENCH MOS SCHOTTKY **BARRIER RECTIFIER**

#### **DESCRIPTION**

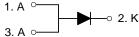
The UTC TGBR30U50 is a trench mos schottky barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high current capability, etc.

The UTC TGBR30U50 suitable for free wheeling, high frequency inverters, polarity protection, and low voltage.

#### **FEATURES**

- \* Ultra low forward voltage drop
- \* High current capability
- \* High surge capability
- \* High efficiency

### **SYMBOL**

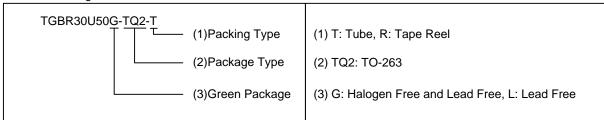




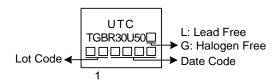
#### **ORDERING INFORMATION**

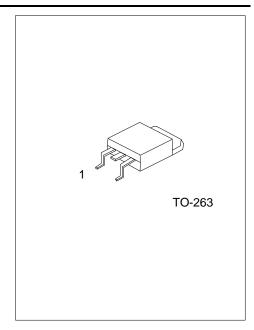
| Ordering Number  |                  | Dardina | Pin Assignment |   |   | Dankina   |  |
|------------------|------------------|---------|----------------|---|---|-----------|--|
| Lead Free        | Halogen Free     | Package | 1              | 2 | 3 | Packing   |  |
| TGBR30U50L-TQ2-T | TGBR30U50G-TQ2-T | TO-263  | Α              | K | Α | Tube      |  |
| TGBR30U50L-TQ2-R | TGBR30U50G-TQ2-R | TO-263  | Α              | K | Α | Tape Reel |  |

Note: Pin Assignment: G: Gate S: Source D: Drain



## **MARKING**





TGBR30U50

## ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

| PARAMETER  | SYMBOL                                      | RATINGS            | UNIT |  |
|--|---|--------------------|------|--|
| DC Blocking Voltage                                    | $V_{RM}$                                    | 50                 | V    |  |
| Working Peak Reverse Voltage                           | $V_{RWM}$                                   | 50                 | V    |  |
| Peak Repetitive Reverse Voltage                        | $V_{RRM}$                                   | 50                 | V    |  |
| Average Rectified Output Current T <sub>C</sub> =125°C | lo  | 30                 | Α    |  |
| Non-Repetitive Peak Forward Surge Current 8.3ms        |   | 380                | ^    |  |
| Single Half Sine-Wave Superimposed on Rated Load       | IFSM  | 380                | А    |  |
| Operating Junction Temperature                         | erating Junction Temperature T <sub>J</sub> |                    | °C   |  |
| Storage Temperature                                    | $T_{STG}$                                   | -65 ~ <b>+</b> 150 | °C   |  |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

# ■ THERMAL CHARACTERISTICS (PER LEG)

| PARAMETER                  | SYMBOL        | RATINGS | UNIT |
|----------------------------|---------------|---------|------|
| Typical Thermal Resistance | $\theta_{JC}$ | 3       | °C/W |

Note: FR-4 PCB, 2 oz Copper. Minimum recommended pad layout.

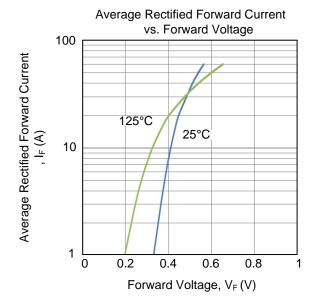
## ■ ELECTRICAL CHARACTERISTICS (PER LEG) (T<sub>A</sub> =25°C unless otherwise specified.)

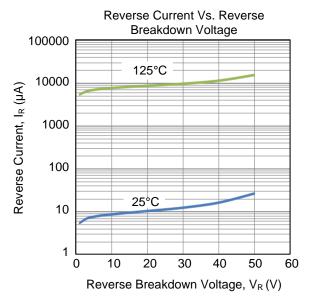
| PARAMETER                 | SYMBOL          | TEST CONDITIONS                            | MIN | TYP  | MAX  | UNIT |
|---------------------------|-----------------|--|-----|------|------|------|
| Reverse Breakdown Voltage | $V_{(BR)R}$     | I <sub>R</sub> =0.5mA                      | 50  |      |      | V    |
| Forward Voltage Drop      | V <sub>FM</sub> | I <sub>F</sub> =5A, T <sub>J</sub> =25°C   |     | 0.4  |      | V    |
|                           |                 | I <sub>F</sub> =5A, T <sub>J</sub> =125°C  |     | 0.3  |      | V    |
|                           |                 | I <sub>F</sub> =15A, T <sub>J</sub> =25°C  |     | 0.42 |      | V    |
|                           |                 | I <sub>F</sub> =15A, T <sub>J</sub> =125°C |     | 0.38 |      | V    |
|                           |                 | I <sub>F</sub> =30A, T <sub>J</sub> =25°C  |     | 0.48 | 0.56 | V    |
|                           |                 | I <sub>F</sub> =30A, T <sub>J</sub> =125°C |     | 0.46 | 0.53 | V    |
| Leakage Current           | I <sub>RM</sub> | V <sub>R</sub> =50V, T <sub>J</sub> =25°C  |     |      | 50   | μΑ   |
|                           |                 | V <sub>R</sub> =50V, T <sub>J</sub> =125°C |     |      | 5    | mA   |

Note: Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%.

TGBR30U50

### ■ TYPICAL CHARACTERISTICS





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